Ni–Al–Cr superalloy as high temperature cathode current collector for advanced thin film Li batteries†

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To obtain full advantage of state-of-the-art solid-state lithium-based batteries, produced by sequential deposition of high voltage cathodes and promising oxide-based electrolytes, the current collector must withstand high temperatures (>600 °C) in oxygen atmosphere. This imposes severe restrictions on the choice of materials for the first layer, usually the cathode current collector. It not only must be electrochemically stable at high voltage, but also remain conductive upon deposition and annealing of the subsequent layers without presenting a strong diffusion of its constituent elements into the cathode. A novel cathode current collector based on a Ni–Al–Cr superalloy with target composition Ni0.72Al0.18Cr0.10 is presented here. The suitability of this superalloy as a high voltage current collector was verified by determining its electrochemical stability at high voltage by crystallizing and cycling of LiCoO2 directly onto it.

1. Introduction

All-solid-state lithium-based batteries (SSBs) are regarded as the next-generation energy storage solution to surpass the physicochemical limit on volumetric/gravimetric energy density and eliminate the risks from the liquid electrolyte.1 Bulk SSBs still face many challenges related to the electrode/electrolyte interface stability2–4 and engineering of the cathode,1,6–8 but thin film SSBs (TF-SSBs) have already demonstrated an outstanding life cycle with 90% capacity retention after 10 000 cycles using the 5 V high voltage cathode LiNi0.5Mn1.5O4 (LMNO).9 Even though the energy density of TF-SSBs is lower compared to the bulk case, they remain a promising energy storage technology for wearables, sensors, lab-on-chip, implantable and other small-sized portable devices,10,11 and most suitable option for applications involving flexible microdevices.12–16 TF-SSBs are generally produced by the sequential growth of each layer in the stack beginning by the cathode current collector (CC), comprising at intermediate stages an annealing step in air or oxygen to crystallize one or more layers.17 Because the optimum crystallization temperature for cathode materials such as LMNO18 and LiCoO2 (LCO),19,20 and fast solid-state electrolytes such as the garnet-type Li2La2Zr2O12 (LLZO) and perovskite-type Li0.17La0.61TiO3 (LLTO) are at least 700–750 °C in order to get the desired phases and attain high ionic conductivity,21–23 the commonly used CCs such as Al cannot withstand such high temperatures in an oxidizing atmosphere without melting or becoming highly insulating. Stainless steels (SSs), on the other hand, are a tempting choice due to their oxidation resistance at high temperature, but it has been shown for LiMn2O4 that both Fe and Cr diffuse into the cathode degrading its performance.24 Similar shortcomings are observed for LCO on SS and are reported in this work.

In a previous work we introduced Cr2N as a high-temperature cathode CC. Even though the material showed feasibility up to 700 °C, we could observe a substantial Cr diffusion at 600 °C.25 To improve the performance at high temperature, Ni-based superalloys are promising candidates for oxidation resistant and high melting point CCs. In the case of Ni–Al–Cr superalloys as the one developed in the present work, benefits arise from combining Al, with well-known self-passivating properties as well as high stability at high voltage once passivated,26 and Cr with good oxidation resistance at high temperature. However, the incorporation ratios should be carefully considered to avoid thick insulating layer formation or out-discussion issues for following cathode material. It has been reported that more than 16 wt% (30 at%) of Al in Ni–Al alloys leads to a parabolic scale growth of a continuous insulating Al2O3 passivation layer.27 As demonstrated by Han et al. the
incorporation of Al into LCO begins already at 400 °C, although after long annealing periods of 8 hours, while in Mn-based cathode materials Al does not diffuse in but results in the formation of the electrical insulator LiAlO2 at 600 °C.29 On the other hand, Cr has a detrimental effect on the performance of LiCoO2 when it forms LiCo1−xCrxO2 with x = 0.2 or above,30 hindering the use of this element alone with Ni. Thus, we selected the Al and Cr-deficient composition Ni0.72Al0.18Cr0.10 as target composition. The simultaneous incorporation of Cr and Al in a Ni superalloy has a synergetic effect on the oxidation resistance, decreasing the minimum amount of these alloying elements required to prevent bulk oxidation compared to Ni–Cr and Ni–Al binary alloys.31 The tunable composition can enlarge the electrochemical window together with a reduced diffusion of Cr and Al into the cathode at 700 °C. We demonstrate a thermally stable Ni–Al–Cr current collector on which LCO can readily crystallize, achieving 80% of the theoretical capacity even without major optimization of the LCO deposition conditions.

2. Experimental

The Ni–Al–Cr (NAC) alloy was deposited as alternating layers of Al, Ni and Cr by electron beam evaporation in a BAK UNI evaporator (evatec) at a pressure of 2 × 10−4 Pa, using a deposition rate of 5 Å s−1 for Al, 10 Å s−1 for Ni and 1 Å s−1 for Cr. The Ni–Al–Cr multilayer was later annealed in vacuum (~5 × 10−2 Pa) at 700 °C for 6 hours in a tube furnace (Carbolite GHA 12/300) to alloy the multilayer. For characterization purposes, MgO-coated silicon wafers (100, boron doped silicon, Prime grade, University wafers) are used as substrate. The MgO interlayer, which prevents the reaction between NAC and silicon at high temperature, was sputtered from a MgO target (99.99% purity, Stanford advanced materials) at a pressure of 0.6 Pa using an Ar to O2 ratio of 60 : 0.5, power density of 3.12 W cm−2, substrate temperature of 100 °C and substrate-to-target distance of 10 cm. MgO was later annealed to 850 °C for 3 hours in air using a heating/cooling ramp of 5 °C per minute to crystallize it.

LCO was deposited by RF magnetron sputtering in an Orion sputtering system (AJA International) in confocal off-axis geometry from a LiCoO2 target (99.9% purity, Edgetech Industries LLC). Three different deposition conditions were employed in order to improve the LCO performance denoted as LP LCO–Ar, LP LCO–O2 and HP LCO–O2. The detailed fabrication parameters are listed in Table 1. All LCO thin films were annealed in air at 700 °C for 1 hour with a heating/cooling ramp of 5 K min−1 in a chamber furnace (Heraeus K114). The total quantity of cathode material in each cell was determined by weighing each substrate before and after deposition of LCO with an analytical balance (Mettler Toledo XS205 Dual Range, 0.01 mg readability).

SE (secondary electron) and BSE (back-scattered electron) images were acquired in a scanning electron microscope (Hitachi FEG-SEM S-4800) working at 5 kV. Energy dispersive X-ray spectroscopy (EDX) spectra were registered at the indicated accelerating voltages using a Bruker XFlash 6/10 X-ray detector with 121 eV resolution at Mn Kz and the standardless quantification was performed with the software ESPRIT from Bruker. X-ray diffractograms were obtained with a Bruker D8 Discover diffractometer using Cu Kz1 radiation in a grazing incidence configuration.

Raman measurements were performed between 300 and 800 cm−1 with a 50× objective, using a Renishaw Raman system equipped with a HeNe Laser, λ = 633 nm.

X-ray photoelectron spectroscopy (XPS) measurements were performed with monochromatized Al Kz X-ray source (PHI Quantum 2000 equipment) at room temperature. The surveys were acquired with 117.4 eV pass energy and single scans with 29.35 eV pass energy. The later provides high-resolution scans with the full-width half maximum of 1 eV. Calibration was performed with the C 1s peak at 285.0 eV. Depth profiles were carried out with an Ar+ ion sputter gun, operated with an acceleration voltage of 2 kV.

For the determination of the resistivity, gold contacts of ~70 nm thickness, spaced as in Fig. S3,† were deposited by thermal evaporation on NAC (420 nm) on sapphire ((0001) orientation, Stettler sapphire). The gold (4N purity) was evaporated at a pressure of 2 × 10−4 Pa and a rate of 1.3 Å s−1 as determined by a quartz crystal microbalance, without intentionally heating the substrates. The area comprising the gold contacts was scribed with a diamond tip in order to minimize edge effects. The resistance between each pair of contacts was determined from the I–V curves using a Keithley 2400 source meter by four-point probe measurements at room temperature and in air. The sample resistance was obtained by the transmission line method. The resistivity was then calculated by multiplying by the contact length (8 mm) and layer thickness (420 nm).

Impedance measurements were conducted using a PAIOS 4.0 system (Fluxim AG). Samples were measured in an LTSE-420-P temperature-controlled stage (Linkam Scientific Instruments Ltd) and the temperature monitored using a PT-100 sensor attached to the sample. The impedance response was measured in the range 10 mHz to 10 MHz with an oscillation amplitude of 10 mV in the temperature range from 297.8 K to 346.9 K in dry air atmosphere, while the fitted range was 10 mHz to 1 MHz. All

Table 1: The deposition parameters of the LiCoO2 thin films

<table>
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<tr>
<th>Condition</th>
<th>Pressure (Pa)</th>
<th>Working gas</th>
<th>Ratio (sccm)</th>
<th>Add substrate bias of 50 V</th>
<th>Target-to-substrate distance (cm)</th>
<th>Deposition rate (Å min⁻¹)</th>
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<tr>
<td>LP LCO–Ar</td>
<td>4 × 10⁻²</td>
<td>Ar</td>
<td>1</td>
<td>No</td>
<td>11.8</td>
<td>11</td>
</tr>
<tr>
<td>LP LCO–O2</td>
<td>0.79</td>
<td>Ar : O2</td>
<td>24 : 1</td>
<td>Yes</td>
<td>11.8</td>
<td>4</td>
</tr>
<tr>
<td>HP LCO–O2</td>
<td>3</td>
<td>Ar : O2</td>
<td>24 : 1</td>
<td>Yes</td>
<td>9.8</td>
<td>&lt;2.5</td>
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</table>
impedance spectra analysis and equivalent circuit simulation were carried out in ZView 2.0 (Scribner Associates, Inc.). Impedance data were validated using a linear Kramers–Kronig method.

Elemental characterizations were performed at the 3 MV tandem accelerator of the National Center for Accelerators (Sevilla, Spain) by proton elastic backscattering spectroscopy (p-EBS). p-EBS was performed with a proton beam of 3.0 MeV and a passivated implanted planar silicon (PIPS) detector at a 160° scattering angle. The Rutherford Backscattering (RBS) spectra were analyzed with the SIMNRA software after subtracting the substrate contribution. Non-Rutherford cross sections were used in the software for Li and O elements.

Secondary ion mass spectrometry (SIMS) measurements were recorded on a TOF-SIMS system from ION-TOF using O₂⁺ primary ions with 2 keV of ion energy, a current of 400 nA, and a raster size of 400 × 400 μm². An area of 100 × 100 μm² was analyzed using Bi⁺ ions with 25 keV of ion energy.

Electrochemical measurements were conducted in air tight coin-type cells, assembled in an Ar-filled glove box (O₂ < 0.1 ppm, H₂O < 0.1 ppm). Elemental lithium was employed as both reference and counter electrode in Li half cells. As electrolyte 1 M LiPF₆ (battery grade, Novolyte) in dimethyl carbonate and ethylene carbonate (1 : 1 EC/DMC by weight, Novolyte) with 3 wt% 4-fluoro-1,3-dioxolan-2-one (FEC, battery grade, Solvionic) was used. Pre-dried glass microfiber (GF/D, Whatman, 80 °C for 12 hours under vacuum) served as separator. LCO cells were cycled between 3–4.25 V vs. Li/Li⁺. All electrochemical measurements were carried out at room temperature on MPG2 multi-channel workstation (BioLogic). Specific capacities and currents were quantified with respect to the mass of the electrode loading.

The electrochemical stability of current collectors was probed by cyclic voltammetry measurements in 1 M LiPF₆ in EC/DMC electrolyte at scan rate of 0.1 mV s⁻¹. The measurements were conducted in Ar-filled glove box (O₂ < 0.1 ppm, H₂O < 0.1 ppm) using elemental lithium and tungsten as reference and counter electrodes, respectively.

3. Results and discussion

The as-deposited Ni–Al–Cr multilayer consists of 10 sequentially evaporated layers as schematized in Fig. 1a in order to facilitate the intermixing of the metals upon annealing. As observed in Fig. 1b, after annealing for 6 hours at 700 °C only 3 fused layers are visible, which is consistent with a Ni-rich alloy. If a fused single layer is intended, then higher temperatures are needed or other deposition techniques such as sputtering should be used.
Here we restricted the annealing temperature to 700 °C in order to reduce alloying between the NAC and the SS substrate in later experiments.

Taking into account the nature of the SS used in this work (Cr content between 16–18.5%), we have prepared an alloy with the target composition Ni$_{0.72}$Al$_{0.18}$Cr$_{0.10}$, which corresponds to weight percentage of 81% of Ni, 9% of Al and 10% of Cr, using a multilayer approach as depicted in Fig. 1a (SEM image presented in Fig. S1†). For the sake of simplicity, this alloy will be called NAC in the following. Once annealed the NAC layer still presents a multilayered structure (Fig. 1b) mainly due to the high melting point of Ni (1453 °C). The estimated composition from EDX measurements (Table ST1†) is Ni$_{0.73}$Al$_{0.06}$Cr$_{0.01}$-Cr$_{0.07}$±0.01. The calculated density for such composition is approximately 8.4 g cm$^{-3}$, which is considerably lighter than Pt (21.45 g cm$^{-3}$) normally used as cathode current collector in Li-based thin film batteries.$^{19,34}$

The electrical resistivity for a 420 nm NAC film is (1.25 ± 0.06) × 10$^{-6}$ Ω m as determined by four-point probe measurements using the transmission line method (Fig. S3†). This value is higher than for NiCr alloys (~1.1–1.2 × 10$^{-6}$ Ω m when Cr is up to 30 wt%$^{35}$) and even higher than for Ni$_3$Al alloys (~4.4 × 10$^{-7}$ Ω m (ref. 36)), which can be attributed to the simultaneous incorporation of Cr and Al into the superalloy. Moreover, the XRD diffractogram in Fig. 1c indicates that the multilayer forms predominantly the solid solution Ni$_3$Al (ICSD 260169) with a small contribution of Ni (Fig. S4†) as indicated by the star, which is in perfect agreement with the work performed by Merchant et al.$^{37}$ on the phase diagrams of the Ni–Al–Cr system, indicating an effective alloying of the multilayer. The difference in peaks intensity and slight shift with respect to the Ni$_3$Al reference pattern can be attributed to the excess of Ni and incorporation of Cr. The TOF-SIMS depth profile in Fig. 1d shows no strong gradient in the profiles for Ni, Cr, and AlO$^+$ (Al signal was saturating). Despite the visible oscillations of the signal, no significant variations in concentration of Al and Cr along the NAC are expected due to the absence of their respective diffraction peaks in the XRD of Fig. 1c.
Both LP LCO-Ar (Fig. 2a) and LP LCO-O2 (Fig. 2b) grown onto the NAC by RF magnetron sputtering show high porosity upon one hour annealing at 700 °C in air and a columnar structure which is more evident for higher thicknesses (Fig. S5†). The TOF-SIMS depth profile for LP LCO-Ar in Fig. 2c does not show severe diffusion of Li and Co into NAC after the annealing process at 700 °C in air for 1 hour. Due to the porous nature of the annealed LCO (Fig. 2a), a broadening of the interfacial region by TOF-SIMS can be expected. The LP LCO-Ar was chosen on purpose for this study due to the high lithium content of the as-prepared film with a Li/Co ratio of ~1.4, as calculated from RBS experiments (Fig. S6a and Table ST2†). Moreover, both Cr⁺ and AlO⁺ signals only show low intensity in the LCO region indicating limited diffusion into the cathode material.

The annealing of LP LCO-Ar films leads to crystalline LCO with preferred orientation in the (003) direction (Fig. 2d), and no secondary phases such as Co₃O₄ are observable. On the other hand, LP LCO-O2 exhibits a less intense (003) diffraction peak and a noticeable (104) reflection (Fig. 2d). For the HP LCO-O2 the (003) reflection in the XRD of Fig. S7b† is completely absent, but the intense peaks at 31.3° and 36.8° are a clearer indication of unwanted formation of secondary phase Co₃O₄. In addition, the SEM cross-section of HP LCO-O2 in Fig. S7a† points out a phase segregation which correlates well with the formation of Co₃O₄. It is generally hypothesized that the (003) texture, contrary to the (101) and (104) ones, does not provide facile diffusion paths for Li ions,38–41 so a negative impact on cathode performance can in principle be expected even for the LP LCO-O2. While in HP LCO-O2 the (003) diffraction peak is absent, the presence of the secondary phase Co₃O₄ might have a detrimental effect on the ionic conductivity of the cathode.

The main peaks in the Raman spectrum of LP LCO-Ar/NAC/MgO/Si in Fig. 2e (top) correspond to the high-temperature phase of LCO,19 but in this case some broad bands around 620–700 cm⁻¹ are an indication of Co₃O₄,42 which is expected to form due to the low sputtering pressure employed, while the band located at 440–470 cm⁻¹ and the lifted background between the two main peaks are mainly attributed to the low-temperature LCO phase.43 As demonstrated by H. Y. Park et al., S. Tintignac et al. and C.-L. Liao et al., the effect of pressure,40,42 bias44 and temperature49 have a dramatic impact on the properties of LCO and its capacity, where sputtering pressures lower than 3 Pa (4 × 10⁻² Pa used for LP LCO-Ar) and the absence of bias lead to overstoichiometric LCO films (Li rich)40,41 and Co₃O₄ formation42,43 which has negative effect on...
the capacity of the cathode. For LP LCO-O2 the two main peaks in the Raman spectrum (Fig. 2e, bottom) become thinner, while the peak at 597 cm$^{-1}$ is now less intense compared to the peak at 487 cm$^{-1}$, an indication of a lower amount of the low-temperature phase. The bump at ~670 cm$^{-1}$ has been assigned by Tintignac et al. to Co$_3$O$_4$, and can be attributed to an unbalanced Li/Co ratio, which for annealed LP LCO-O2 films is ~1.1 (Fig. S6b and Table ST2†).

SEM top view images in Fig. 3a–c show the surface morphology of LP LCO-Ar annealed at 700 °C in air for 1 hour on different substrates. If grown on NAC/MgO/Si (Fig. 3a) small irregular crystals ≤100 nm dominate the surface of LCO, while in the case of NAC/SS (Fig. 3b) there are also larger dispersed crystals segregated on the surface which can be attributed to Cr diffusion as reported in our previous work. This is further supported by the XPS depth profile for Cr in Fig. S8. For NAC/MgO/Si Cr signal is in the noise level throughout the LCO layer (Fig. S8a†), whereas for NAC/SS the Cr signal is more intense close to the surface and decreases towards the current collector (Fig. S8b†). On the other hand, on SS (Fig. 3c) considerably larger grains (>300 nm) are mostly observed.

According to the XRD figures of annealed LP LCO-Ar on NAC/SS (Fig. 3d), the NAC diffraction peaks are shifted to lower angles (43.74°) due to the alloying with SS (named as SS alloy in the figure). Moreover, we attribute the small peak at 31.28° to Co$_3$O$_4$ (Fig. 3d). The amount of Fe incorporated into NAC estimated by EDX is around 14–15%, while there is also an increase of the at% of Cr (Fig. S2 and Table ST1†). Despite the meaningful amount of incorporated Fe (but considerably lower than for SS), the surface chemistry of these alloys is still determined by the selective oxidation of Al and, to a lower extent, Cr. On SS, however, besides the main (003) reflection, numerous peaks which we attribute to Fe$_3$O$_4$ can be observed (Fig. 3d). The XPS surveys in Fig. 3e indicate the presence of Cr in LCO (~200 nm) annealed on NAC/SS, while a small signal for Al and none for Fe can be identified (Fig. 3e). Furthermore, the position of the Al 2p peak at 73.0 eV is too low in energy to correspond to Al$_2$O$_3$ (74.3 eV) or LiAlO$_2$ (74.1 eV) and it has been assigned in literature to LiCo$_{1-x}$Al$_x$O$_2$. On the other hand, the surface survey for LCO (~200 nm thick) annealed on SS indicates diffusion of Fe, Cr, Mn and Mo, which can lead to the formation of large crystals on the surface by heterogeneous nucleation (Fig. 3c). In both surveys contribution from the substrate cannot be completely discarded due to the porosity of LCO and eventual cracks. However, it can be expected that the majority of the signal arises from the LCO layer.

Through-plane impedance measurements were carried on gold-coated LP LCO-O2 (~430 nm)/NAC/sapphire as shown in Fig. 4. This LCO was chosen due to its better electrochemical performance (see discussion below). A simple Debye circuit does not yield a satisfactory fitting of the Nyquist plot. As reported in literature, a resistor needs to be added in parallel to account for the mixed conductor behavior (i.e. a combination of ionic and electronic conductivities) of LCO. This results in the depicted equivalent circuit (Fig. 4a), composed of a geometric capacitance in parallel with a series $R_{\text{ion}}$-$C_{\text{int}}$ configuration (modeling ionic conductivity and interfacial capacitance
through the material) and a resistor $R_e$ (modeling electronic conductivity).\textsuperscript{48} In the fitting, constant phase elements (CPE) are used instead of ideal capacitors to model the non-idealities of the interfacial charge transfer (see ESI† for more details on the interpretation). A series resistance $R_s$ is added to account for the contact resistance.

The effects of ionic transport through grain boundaries are not observed in the impedance spectrum, which can be explained from the columnar morphology of LCO (Fig. 2a and S5†) and hence its low number of grain boundaries in the through-plane direction. In addition, no meaningful variation in the impedance is expected from the evaporated gold on the sample due to its negligible penetration into LCO as observed in the SEM (Fig. 4b top) and BSE (Fig. 4b bottom) images.

The evolution of the impedance as temperature increases is plotted in Fig. 4a, where a noticeable shrinking of the arcs is observed for higher temperatures. A\textsuperscript{50} verifying that the data satisfied the Kramers–Kronig conditions, with deviations below 2% over the whole frequency range (Fig. S9†), all data were fitted with the equivalent circuit in Fig. 4a. The values of the different fitted parameters are reported in Table ST3† along with a brief discussion concerning their physical meaning. The electronic and ionic conductivity values for the measured temperature range are summarized in Table ST4,\textsuperscript{†} yielding $\sim 0.6 \times 10^{-10}$ S cm$^{-1}$ and $\sim 2.0 \times 10^{-10}$ S cm$^{-1}$ at RT, respectively. Although these seem rather low values, it is difficult to establish any comparison with other works due to the lack of literature related to direct measurements of LCO thin films, without any delithiation treatment by liquid electrolyte or conductive additive. But it is worth mentioning that the fully lithiated LiCoO$_2$ is at least 4 orders of magnitude less electronically conductive in the majority of published literature.\textsuperscript{49–51}

Moreover, the preferred orientation and film porosity may also influence the measured conductivity.\textsuperscript{52,53} According to our previous results, our sputtered LCO thin presents (003) preferred orientation and highly porous morphology. All of these factors may play a role in the low electronic conductivity of the measured LCO.

Two activation energies can be differentiated in the Arrhenius-type plot (Fig. 4c) with values of 0.34 eV and 0.30 eV for the ionic and electronic transport, respectively (Table ST5†). These values are in agreement with previously reported ones in literature (0.2–0.45 eV) associated to the electronic and ionic transport phenomena in LCO.\textsuperscript{49,54–59} Notice that this value is considerably lower than for LiAlO$_2$, which lays above 0.7 eV in the temperature range RT-200 °C,\textsuperscript{60} discarding the formation of this compound in a significant amount in agreement with Han et al.\textsuperscript{29} and XPS (Fig. 3e). Moreover, the estimated series resistance at room temperature is $\sim 2.3 \Omega$ cm$^2$ (Table ST3†),
suggesting a good ohmic contact between LCO and NAC, while the absence of a high capacitance in the impedance spectra (Fig. 4a) also discards the formation of a thick insulating Al2O3 layer at the NAC-LCO interface.

The electrochemical response of the NAC layer was determined in LiPF6 electrolyte in order to assess its stability at high voltage. As seen in Fig. 5a the current density observed with NAC is significantly lower than that of SS and lower also than of Al, which is used as standard current collector in most Li-based batteries. Although Cr and Ni are not stable up to 5 V vs. Li/Li+, the passivated Al with alumina or AlF3 formed by reaction with the electrolyte serves as good passivation layers at high voltage.43 This explains the observed superior stability of the NAC layers since aluminium is dominating the surface chemistry when oxidation processes are involved.

The electrochemical behavior of LCO not only depends on the sputtering conditions23,41,42 but also on the substrate used as support as observed in the cyclic voltammograms of Fig. 5b. LP LCO-Ar on bare SS presents a quite poor electrochemical response in the potential range 3–4.25 V vs. Li/Li+. On the other hand, LP LCO-Ar on NAC exhibits better-defined peaks. Furthermore, for the more optimized deposition conditions of LP LCO-O2 (Fig. 5b), attained by increasing the pressure, introducing a small amount of oxygen and adding a bias, the shape of the peaks become more pronounced. Our results are in line with literature where it was demonstrated that an increase in pressure and the use of a bias led to better-defined peaks and an overall improved electrochemical response.19,40,42,43

The galvanostatic charge and discharge curves of Fig. 5c evidence an extremely low capacity for LCO on SS of ~13 mA h g⁻¹ even for a ~200 nm thick layer. Kalaiselvi et al. observed a steadily decrease in the capacity of LiCoO2–Fe2O3 upon incorporation of higher amounts of iron (up to y = 0.4), accompanied by lower coulombic efficiencies, although no explanation for this behavior was given.63 However, here we attribute such low capacity to the formation of Fe3O4 (Fig. 3c–e) rather than substitution of Co by Fe in LCO, which exhibits electrochemical response below 2.5 V vs. Li/Li+. The capacity of LCO on NAC is significantly increased from ~97 mA h g⁻¹ (LP LCO-Ar) to ~108 mA h g⁻¹ (LP LCO-O2), Fig. 5c. A capacity fade is observed in all cases (Fig. 5d) which is usual in these thin film systems coupled to a liquid electrolyte.19,42,43 The HP LCO-O2 sputtered using optimum deposition conditions (according to literature) yielded a much lower capacity of ~72 mA h g⁻¹ (Fig. S10f) which is in agreement with the more intense Co3O4 peak in XRD (Fig. S7b†). This difference with regard to literature is attributed to our confocal off-axis sputtering configuration, limiting the deposition rate in HP LCO-O2 below 2.5 Å min⁻¹. Such low rates can lead to substantial re-sputtering during the deposition process yielding more Co3O4 as observed here. Moreover, the O2 partial pressure employed in this work was below 1 mbar, however a higher pressure would be desirable to avoid O2 deficiency in the sputtered films, but this would lead in our system to even lower rates and higher re-sputtering.19

4. Conclusions

In this study, we report a high temperature stable Ni-Al-Cr superalloy with resistivity 1.25 × 10⁻⁶ ± 6 × 10⁻⁸ Ω m for target composition Ni₆₋₇Cr₆₋₅Al₃₋₁₉. The detailed TOF-SIMS and XPS indicate that the Ni-Al-Cr superalloy exhibited restricted Al and Cr elements out-diffusion into the LiCoO₂ cathode and suppressed Fe and Cr diffusion from the stainless steel substrate when NAC was implemented as a diffusion barrier on SS after 700 °C annealing.

Impedance spectroscopy analysis at different temperatures for LCO on NAC show the activation energies of 0.30 eV (electronic) and 0.34 eV (ionic), excluding LiAlO2 formation as a result of the high temperature processing, while the low series resistance of 2.3 Ω cm² also excludes the presence of a thick insulating Al2O3 layer at the LCO/NAC interface.

The suitability as high voltage current collector is verified by the low current density (<2 μA cm⁻²) observed at 5 V vs. Li/Li⁺ in the first scan. The electrochemical performance of LCO processed on NAC/SS is greatly superior to that on bare SS, achieving an initial discharge capacity of ~108 mA h g⁻¹ and ~13 mA h g⁻¹, respectively. In order to further improve the performance of LCO on NAC it is mandatory to optimize the deposition conditions of the former, eliminating the (001) texture while minimizing Co3O4 formation.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work was supported by the Swiss National Science Foundation [grant numbers 200021_172764] and Ministry of Science and Technology, R. O. C. [grant numbers 106-2917-I-564-001-AI]. We are grateful to the Laboratory for Energy Conversion Materials and the Laboratory for Nanoscale Materials Science at Empa in Duebendorf, Switzerland, for giving access to XRD, TOF-SIMS and XPS equipment.

References


